

EMB1AF THRU EMB1JF

1.0A SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIER



FEATURES

- * Ideal for printed circuit board
- * Reliable low cost construction utilizing molded plastic technique
- * High surge current capability
- * Polarity: Symbol molded on body
- * Mounting position: Any
- * Weight: 0.12 grams

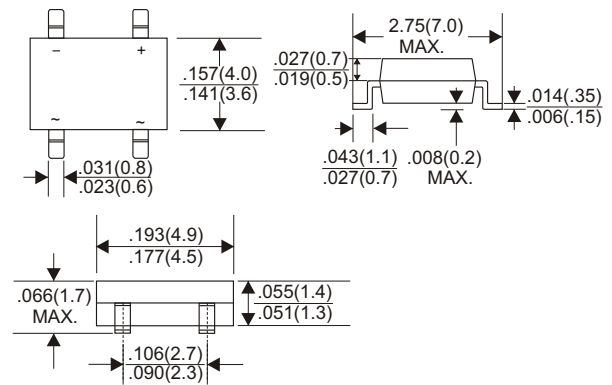
VOLTAGE RANGE

50 to 1000 Volts

CURRENT

1.0 Ampere

MBF



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.
Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

TYPE NUMBER	EMB1AF	EMB1BF	EMB1CF	EMB1DF	EMB1EF	EMB1GF	EMB1JF	UNIT
Maximum Recurrent Peak Reverse Voltage	50	100	150	200	300	400	600	V
Maximum RMS Voltage	35	70	105	140	210	280	480	V
Maximum DC Blocking Voltage	50	100	150	200	300	400	600	V
Maximum Average Forward Rectified Current at Ta=25°C	1.0							A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	30							A
Maximum Forward Voltage Drop per Bridge Element at 1.0A.	1.0			1.3		1.7		V
Maximum DC Reverse Current at Rated DC Blocking Voltage	5.0			200				μA
Maximum Reverse Recovery Time (Note 1)	35							nS
Typical Junction Capacitance (Note 2)	15							pF
Typical Thermal Resistance R _{JA} (Note 3)	80							°C/W
Operating and Storage Temperature Range T _J , T _{STG}	-65 — +150							°C

NOTES:

1. Reverse Recovery Time test condition: IF=0.5A, IR=1.0A, IRR=0.25A
2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
3. Thermal Resistance from Junction to Ambient.

RATING AND CHARACTERISTIC CURVES (EMB1AF THRU EMB1JF)

FIG.1- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

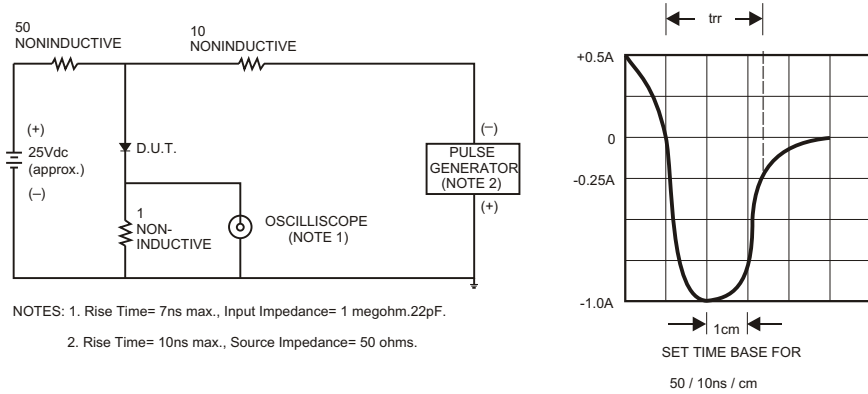


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

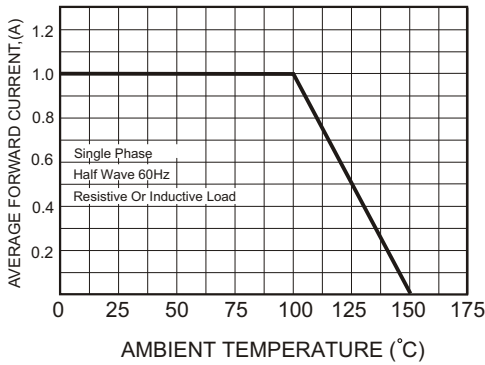


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

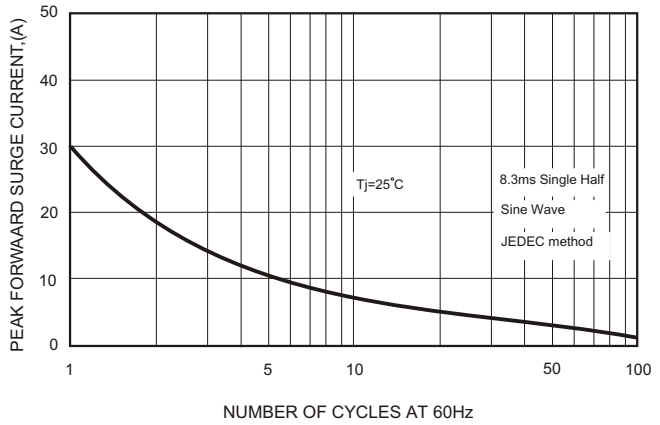


FIG.4-TYPICAL FORWARD CHARACTERISTICS

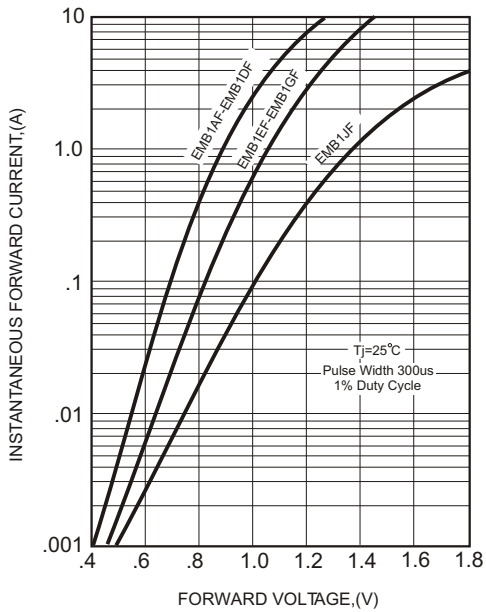


FIG.5-TYPICAL REVERSE CHARACTERISTICS

